



# Photointerrupter Product Data Sheet

LTH-301-07

Spec No.: DS-55-92-0003

Effective Date: 06/29/2000

Revision: A

**LITE-ON DCC**

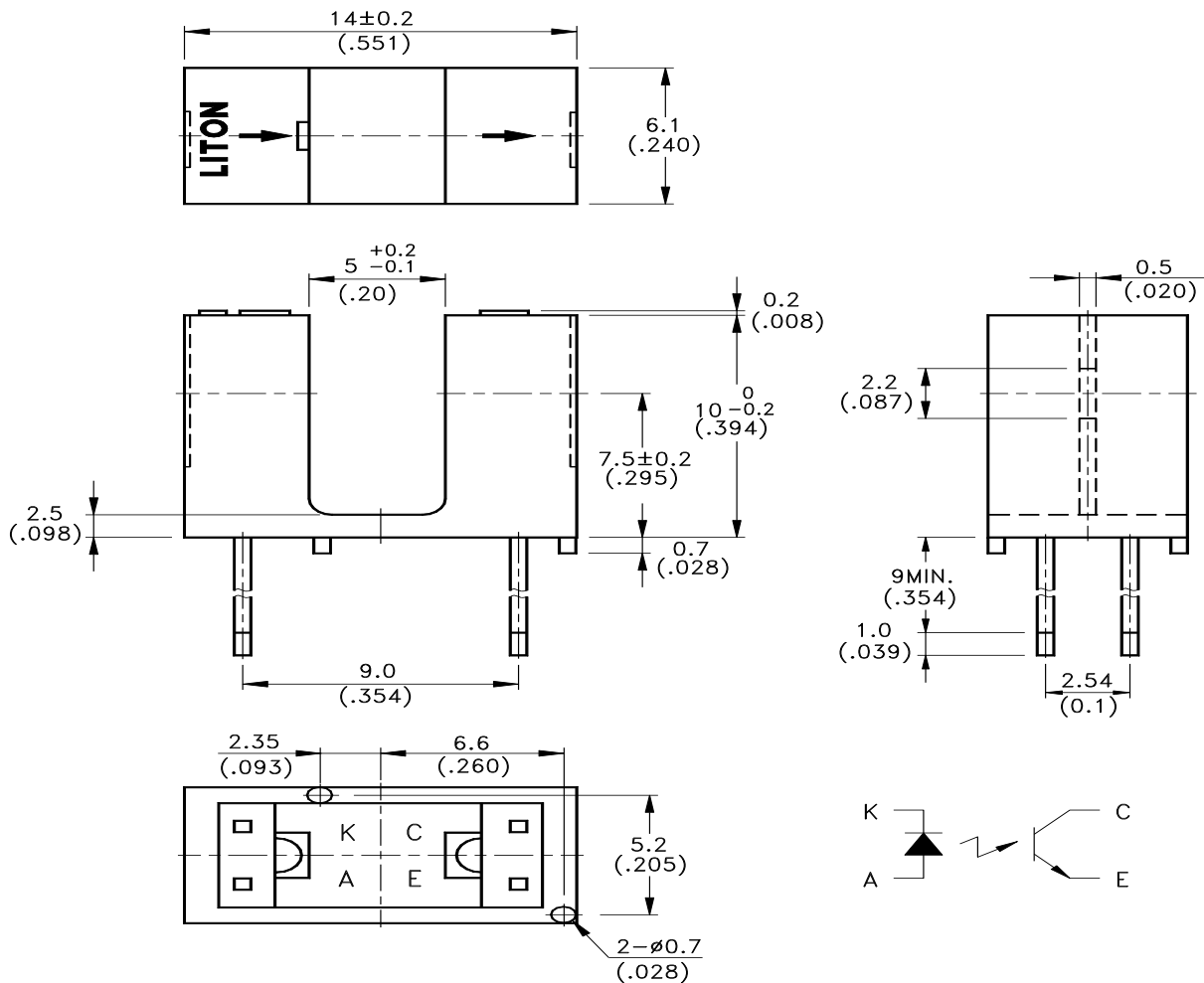
**RELEASE**

BNS-OD-FC001/A4

## FEATURES

- \* NON-CONTACT SWITCHING.
- \* FOR DIRECT PC BOARD OR DUAL-IN-LINE SOCKET MOUNTING.
- \* FAST SWITCHING SPEED.

## PACKAGE DIMENSIONS



## NOTES:

1. All dimensions are in millimeters (inches).
2. Tolerance is  $\pm 0.25$ mm(.010") unless otherwise noted.

## ABSOLUTE MAXIMUM RATINGS AT TA=25°C

PARAMETER	MAXIMUM RATING	UNIT
IR Diode Continuous Forward Current	60	mA
IR Diode Reverse Voltage	5	V
Transistor Collector Current	20	mA
Transistor Power Dissipation	75	mW
IR Diode Peak Forward Current (Pulse Wide = 10 $\mu$ S, 300 pps)	1	A
Diode Power Dissipation	100	mW
Phototransistor Collector-Emitter Voltage	30	V
Phototransistor Emitter-Collector Voltage	5	V
Operating Temperature Range	-25°C to + 85°C	
Storage Temperature Range	-40°C to + 100°C	
Lead Soldering Temperature [1.6mm(.063") From Case]	260°C for 5 Seconds	

## ELECTRICAL OPTICAL CHARACTERISTICS AT TA=25°C

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
<b>INPUT LED</b>						
Forward Voltage	V <sub>F</sub>		1.2	1.6	V	I <sub>F</sub> = 20mA
Reverse Current	I <sub>R</sub>			100	μA	V <sub>R</sub> =5V
<b>OUTPUT PHOTOTRANSISTOR</b>						
Collector-Emitter Breakdown Voltage	V(BR) <sub>CEO</sub>	30			V	I <sub>C</sub> =1mA
Emitter-Collector Breakdown Voltage	V(BR) <sub>ECO</sub>	5			V	I <sub>E</sub> =100 μA
Collector-Emitter Dark Current	I <sub>CEO</sub>			100	nA	V <sub>CE</sub> =10V
<b>COUPLER</b>						
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>			0.4	V	I <sub>C</sub> =0.25mA I <sub>F</sub> =20mA
On State Collector Current	I <sub>c(ON)</sub>	0.6			mA	V <sub>CE</sub> =5V I <sub>F</sub> =20mA
Response Time	Rise Time	t <sub>r</sub>	3	15	μS	V <sub>CE</sub> =5V, I <sub>c</sub> =2mA R <sub>L</sub> =100Ω
	Fall Time	t <sub>f</sub>	4	20		

## TYPICAL ELECTRICAL / OPTICAL CHARACTERISTICS CURVES

(25°C Ambient Temperature Unless Otherwise Noted)

Fig.1 Power Dissipation vs. Ambient Temperature

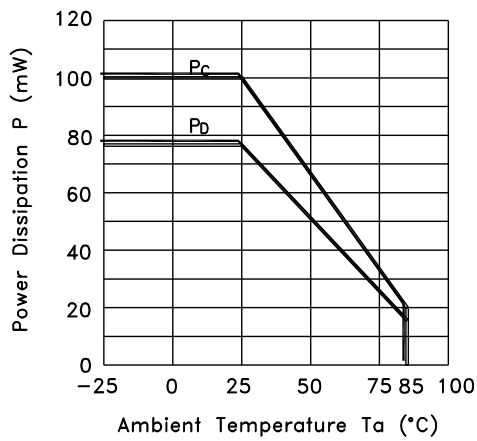


Fig.2 Forward Current vs. Forward Voltage

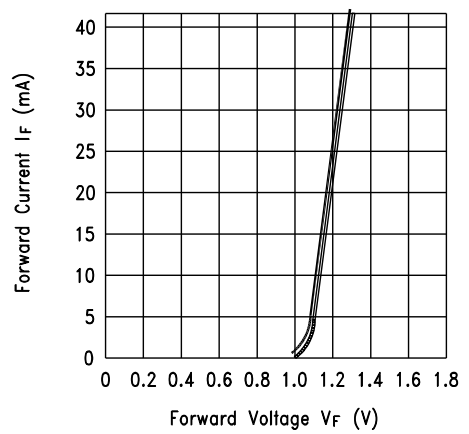


Fig.3 Collector Current vs. Forward Voltage

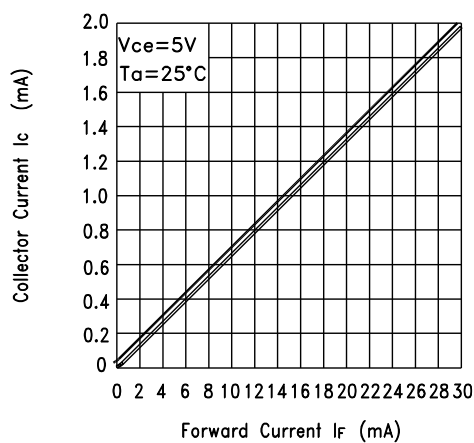
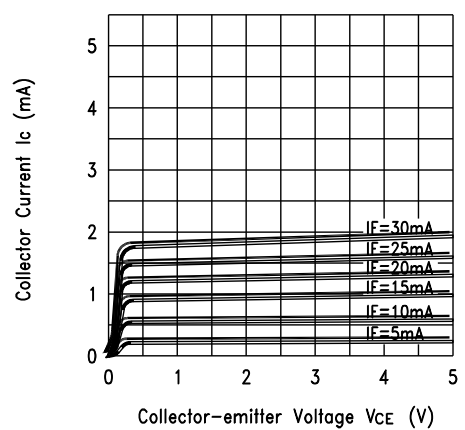


Fig.4 Collector Current vs. Collector-emitter Voltage



## TYPICAL ELECTRICAL / OPTICAL CHARACTERISTICS CURVES

(25°C Ambient Temperature Unless Otherwise Noted)

Fig.5 Collector Current vs. Ambient Temperature

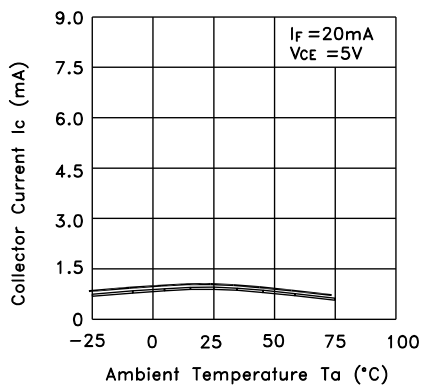


Fig.6 Collector-emitter Saturation Voltage vs. Ambient Temperature

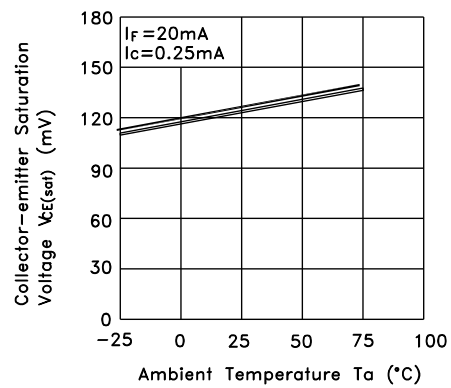
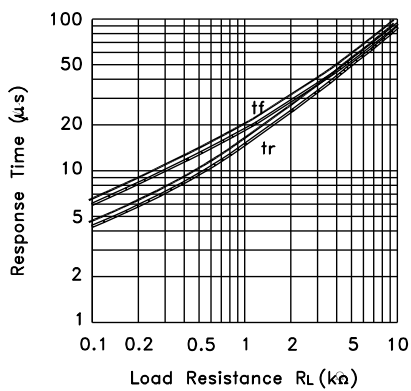
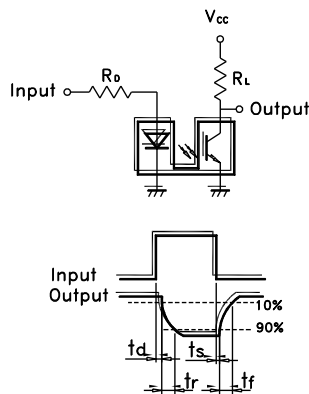


Fig.7 Response Time vs. Load Resistance



Test Circuit for Response Time



## X-ON Electronics

Largest Supplier of Electrical and Electronic Components

*Click to view similar products for* [Optical Switches, Transmissive, Phototransistor Output](#) *category:*

*Click to view products by* [Lite-On](#) *manufacturer:*

Other Similar products are found below :

[LTH-301-07](#) [LTH-301-23](#) [E3C-X2C](#) [E3S-LS20B4S1](#) [E3SX2CE4](#) [RPI-0125B](#) [RPI-2501](#) [RPI-576A](#) [KRA021](#) [LTH-306-04M](#) [LTH-309-08](#)  
[HOA0865-100](#) [HOA1961-055](#) [E3F-3C4](#) [LTH-306-01](#) [EESX677C1JR01M](#) [SIT506F-A](#) [HOA1883-501](#) [PT928-6B-F](#) [RPI-243](#) [EE-SX675P-](#)  
[WR 1M](#) [OPB806](#) [EE-SX1128](#) [OPB857Z](#) [EE-SV3-B](#) [EE-SJ3-D](#) [RPI-0226](#) [EE-SX951P-W 1M](#) [EE-SX672R](#) [EE-SX670P-WR 1M](#) [LTH-301-](#)  
[32](#) [EESX674PWR1M](#) [EE-SX952-W 1M](#) [RPI-0352E](#) [RPI-352C40N](#) [DY-ITR002](#) [DY-ITR1100](#) [DY-ITR9909-W2](#) [HOA0825-001](#) [HOA0825-](#)  
[003](#) [HOA0860-N51](#) [HOA0861-N55](#) [HOA0861-P55](#) [HOA0861-T55](#) [HOA0866-P55](#) [HOA0866-T55](#) [HOA0867-P55](#) [HOA0867-T55](#)  
[HOA0870-T51](#) [HOA0871-L55](#)